

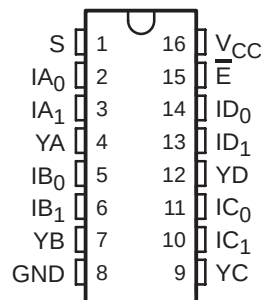
TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

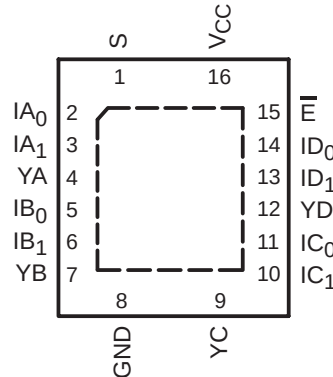
SCDS161A – MAY 2004 – REVISED OCTOBER 2004

- Wide Bandwidth (BW = 350 MHz Min)
- Low Differential Crosstalk ($X_{TALK} = -68$ dB Typ)
- Low Power Consumption ($I_{CC} = 10$ μ A Max)
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance ($r_{on} = 5$ Ω Typ)
- Rail-to-Rail Switching on Data I/O Ports (0 to V_{CC})
- V_{CC} Operating Range From 3 V to 3.6 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Data and Control Inputs Have Undershoot Clamp Diodes
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Suitable for Both 10 Base-T/100 Base-T Signaling

D, DBQ, DGV, OR PW PACKAGE
(TOP VIEW)



RGY PACKAGE
(TOP VIEW)



description/ordering information

The TI TS3L100 LAN switch is a 4-bit 1-of-2 multiplexer/demultiplexer with a single switch-enable ($\bar{E}$) input. When $\bar{E}$ is low, the switch is enabled and the I port is connected to the Y port. When $\bar{E}$ is high, the switch is disabled and the high-impedance state exists between the I and Y ports. The select (S) input controls the data path of the multiplexer/demultiplexer.

ORDERING INFORMATION

T_A	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	QFN – RGY	Tape and reel	TS3L100RGYR	TK100
	SOIC – D	Tube	TS3L100D	TS3L100
		Tape and reel	TS3L100DR	
	SSOP (QSOP) – DBQ	Tape and reel	TS3L100DBQR	TK100
	TSSOP – PW	Tube	TS3L100PW	TK100
		Tape and reel	TS3L100PWR	
	TVSOP – DGV	Tape and reel	TS3L100DGVR	TK100

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

description/ordering information (continued)

This device can be used to replace mechanical relays in LAN applications. This device has low r_{on} , wide bandwidth, and low differential crosstalk, making it suitable for 10 Base-T, 100 Base-T, and various other LAN applications.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, $\bar{E}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE

INPUTS		INPUT/OUTPUT YX	FUNCTION
$\bar{E}$	S		
L	L	IX_0	$YX = IX_0$
L	H	IX_1	$YX = IX_1$
H	X	Z	Disconnect

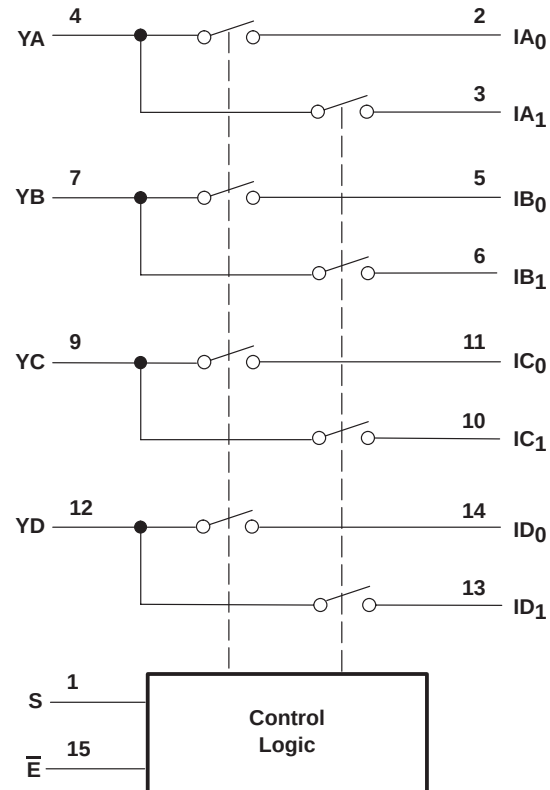
PIN DESCRIPTIONS

PIN NAME	DESCRIPTION
$IAn-IDn$	Data I/Os
S	Select input
$\bar{E}$	Enable input
YA-YD	Data I/Os

TS3L100
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SCDS161A – MAY 2004 – REVISED OCTOBER 2004

logic diagram (positive logic)



TS3L100

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SCDS161A – MAY 2004 – REVISED OCTOBER 2004

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 4.6 V
Control input voltage range, V_{IN} (see Notes 1 and 2)	–0.5 V to 4.6 V
Switch I/O voltage range, $V_{I/O}$ (see Notes 1, 2, and 3)	–0.5 V to 4.6 V
Control input clamp current, I_{IK} ($V_{IN} < 0$)	–50 mA
I/O port clamp current, $I_{I/OK}$ ($V_{I/O} < 0$)	–50 mA
ON-state switch current, $I_{I/O}$ (see Note 4)	±128 mA
Continuous current through V_{CC} or GND terminals	±100 mA
Package thermal impedance, θ_{JA} (see Note 5): D package	73°C/W
DB package	82°C/W
DBQ package	90°C/W
PW package	108°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltages are with respect to ground, unless otherwise specified.
 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 3. V_I and V_O are used to denote specific conditions for $V_{I/O}$.
 4. I_I and I_O are used to denote specific conditions for $I_{I/O}$.
 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	3	3.6	V
V_{IH}	High-level control input voltage ($\bar{E}$, S)	2	V_{CC}	V
V_{IL}	Low-level control input voltage ($\bar{E}$, S)	0	0.8	V
T_A	Operating free-air temperature	0	70	°C

NOTE 6: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

**electrical characteristics over recommended operating free-air temperature range,
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V_{IK}	$\bar{E}, S$	$V_{CC} = 3\text{ V}, I_{IN} = -18\text{ mA}$			-1.8	V
V_{hys}	$\bar{E}, S$			150		mV
I_{IH}	$\bar{E}, S$	$V_{CC} = 3.6\text{ V}, V_{IN} = V_{CC}$			± 1	μA
I_{IL}	$\bar{E}, S$	$V_{CC} = 3.6\text{ V}, V_{IN} = \text{GND}$			± 1	μA
$I_{OZ}^{\ddagger}$		$V_{CC} = 3.6\text{ V}, V_O = 0\text{ to }3.6\text{ V}, V_I = 0,$ Switch OFF			± 1	μA
$I_{OS}^{\S}$		$V_{CC} = 3.6\text{ V}, V_O = 0\text{ to }0.5 V_{CC}, V_I = 0,$ Switch ON	50			mA
I_{off}		$V_{CC} = 0, V_O = 0\text{ to }3.6\text{ V}, V_I = 0$			15	μA
I_{CC}		$V_{CC} = 3.6\text{ V}, I_{I/O} = 0,$ Switch ON or OFF		0.1	10	μA
ΔI_{CC}	$\bar{E}, S$	$V_{CC} = 3.6\text{ V},$ One input at $V_{CC} - 0.6\text{ V},$ Other inputs at V_{CC} or GND			750	μA
I_{CCD}		$V_{CC} = 3.6\text{ V},$ I and Y ports open, V_{IN} input switching 50% duty cycle			0.45	mA/ MHz
C_{IN}	$\bar{E}, S$	$f = 1\text{ MHz}$		3		pF
C_{OFF}	I port	$V_I = 0, f = 1\text{ MHz},$ Outputs open, Switch OFF		5		pF
	Y port			10		
C_{ON}		$V_I = 0, f = 1\text{ MHz},$ Outputs open, Switch ON		17		pF
r_{on}		$V_{CC} = 3\text{ V}, V_I = 0\text{ V}, I_O = 48\text{ mA}$	5	7		Ω
		$V_I = 2\text{ V}, I_O = 15\text{ mA}$	10	15		
Δr_{on}		$V_I = 3\text{ V},$ Switch ON, $I_O = 15\text{ mA}$		1		Ω

$V_I, V_O, I_I,$ and I_O refer to I/O pins. V_{IN} refers to the control inputs.

[†] All typical values are at $V_{CC} = 3.3\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.

[‡] For I/O ports, the parameter I_{OZ} includes the input leakage current.

[§] The I_{OS} test is applicable to only one ON channel at a time. The duration of this test is less than one second.

**switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}, R_L = 100\ \Omega, C_L = 35\text{ pF}$ (unless otherwise noted) (see Figure 4)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	UNIT
t_{ON}	S	Y	1	7.5	ns
t_{OFF}	S	Y	1	3.5	ns

[†] All typical values are at $V_{CC} = 3.3\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.

**dynamic characteristics over recommended operating free-air temperature range,
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	TYP [†]	UNIT
$X_{TALK}(\text{Diff})$	$R_L = 100\ \Omega, f = 10\text{ MHz},$ see Figure 8, $t_r = t_f = 2\text{ ns}$	-55	dB
X_{TALK}	$R_L = 100\ \Omega, f = 30\text{ MHz},$ see Figure 6	-68	dB
O_{IRR}	$R_L = 100\ \Omega, f = 30\text{ MHz},$ see Figure 7	-42	dB
BW	$R_L = 100\ \Omega,$ see Figure 5	350	MHz

[†] All typical values are at $V_{CC} = 3.3\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.



TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

OPERATING CHARACTERISTICS

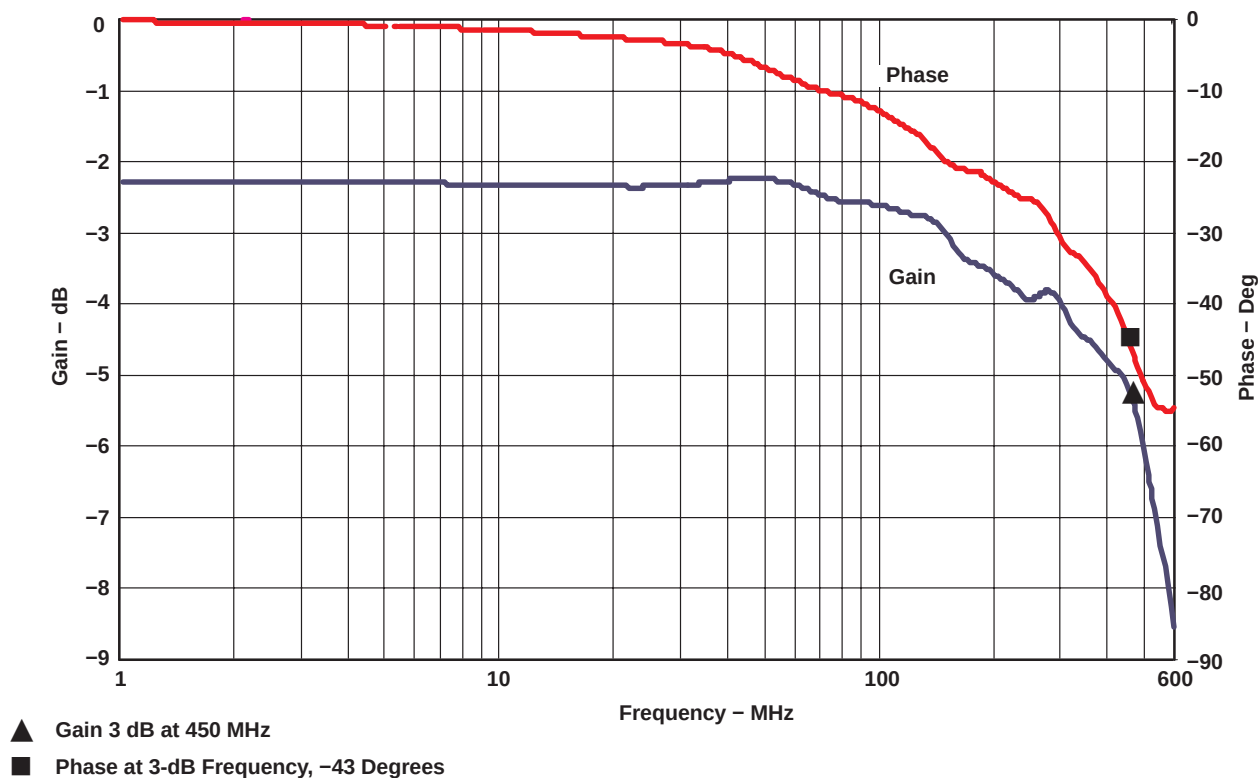


Figure 1. Gain/Phase vs Frequency

OPERATING CHARACTERISTICS

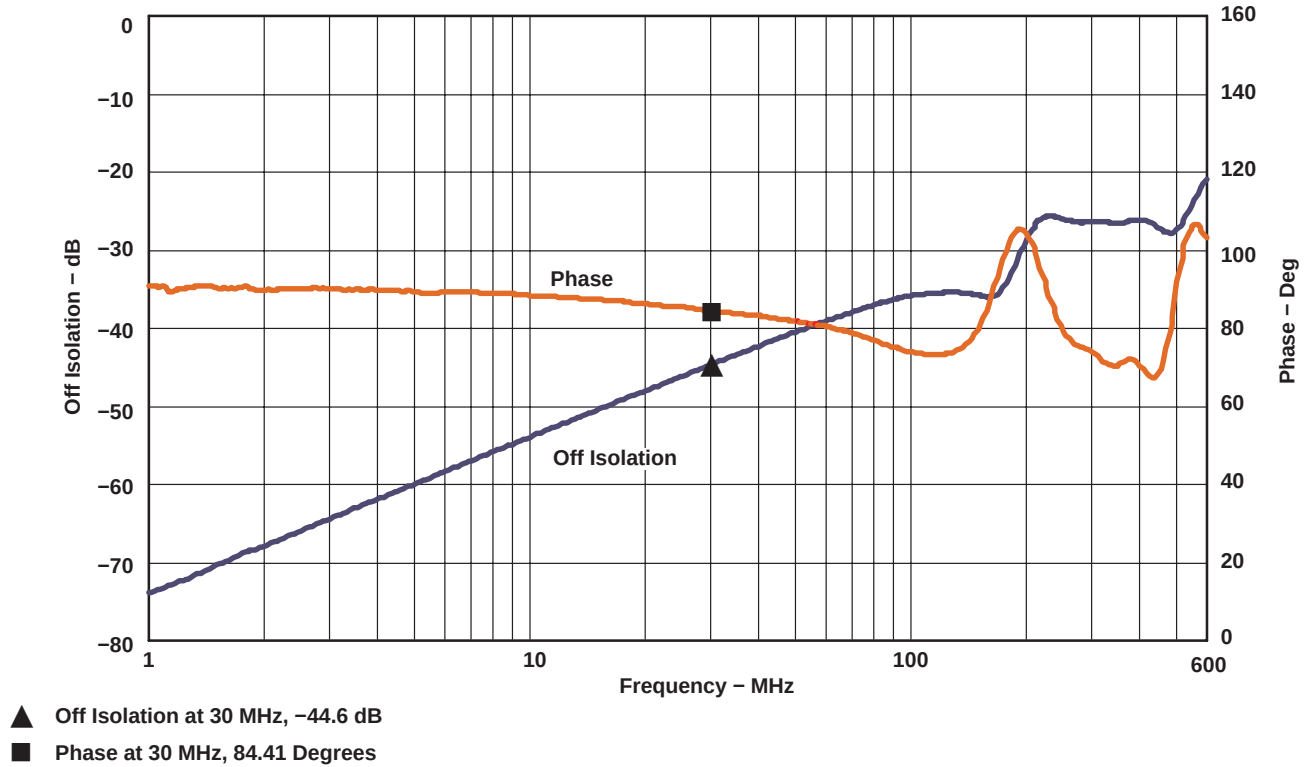


Figure 2. Off Isolation vs Frequency

TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH

WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

OPERATING CHARACTERISTICS

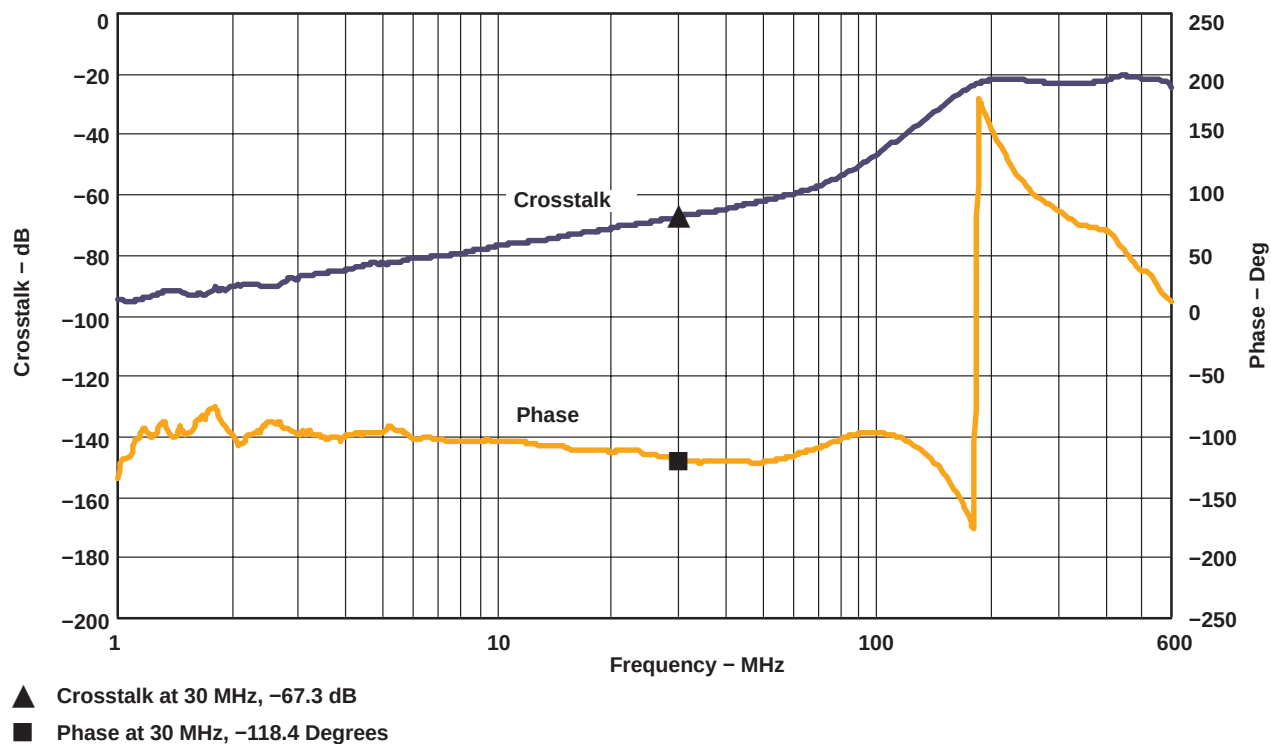
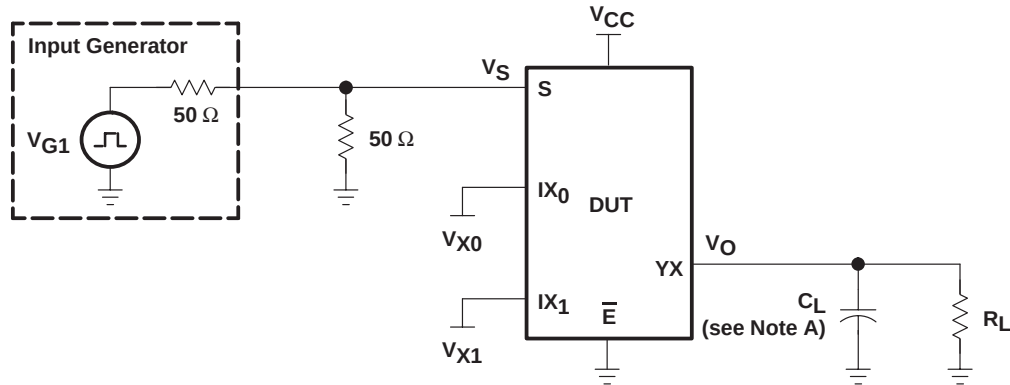


Figure 3. Crosstalk vs Frequency

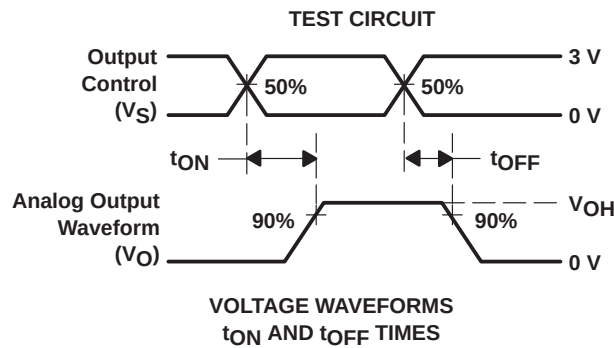
TS3L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

PARAMETER MEASUREMENT INFORMATION



TEST	V _{CC}	R _L	C _L	V _{X0}	V _{X1}
t _{ON}	3.3 V ± 0.3 V	100 Ω	35 pF	GND	3 V
	3.3 V ± 0.3 V	100 Ω	35 pF	3 V	GND
t _{OFF}	3.3 V ± 0.3 V	100 Ω	35 pF	GND	3 V
	3.3 V ± 0.3 V	100 Ω	35 pF	3 V	GND



- NOTES: A. C_L includes probe and jig capacitance.
 B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
 C. The outputs are measured one at a time, with one transition per measurement.

Figure 4. Test Circuit and Voltage Waveforms

TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

PARAMETER MEASUREMENT INFORMATION

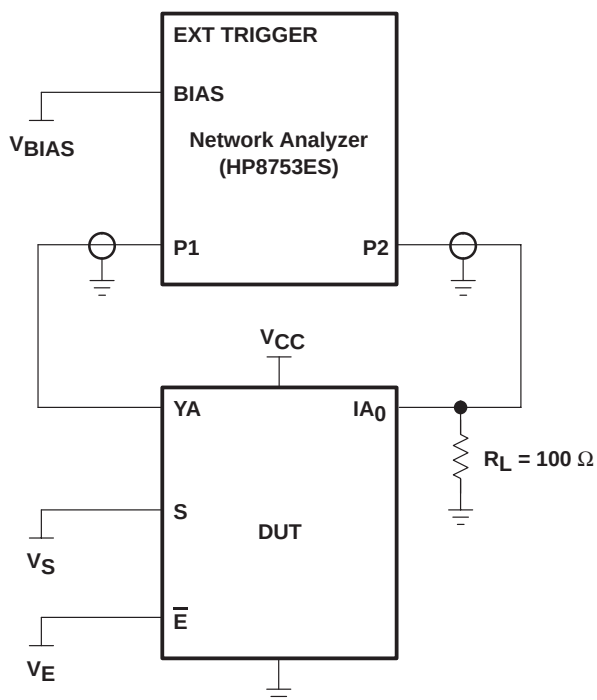


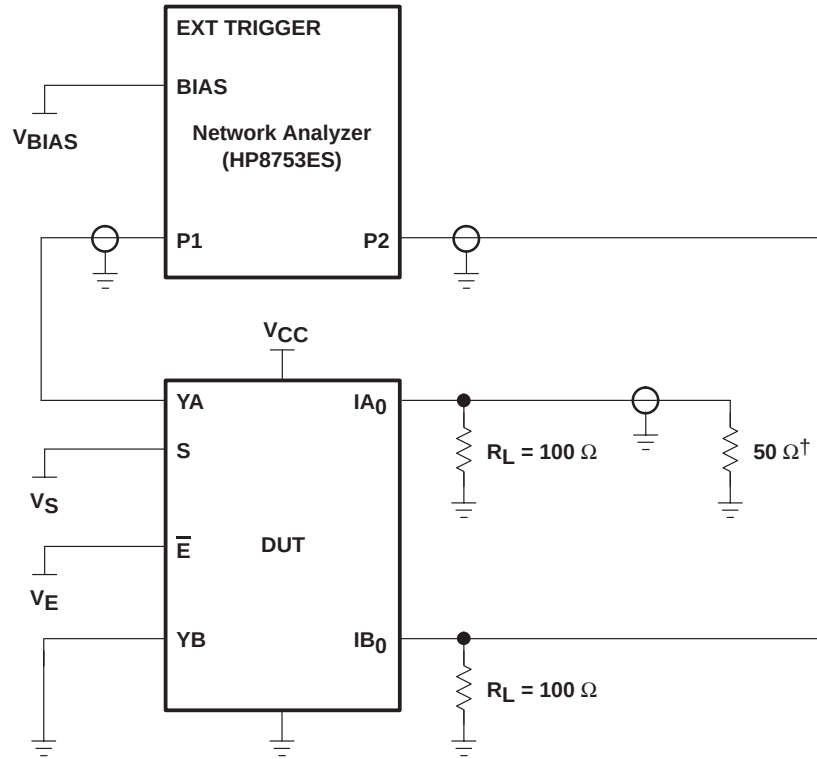
Figure 5. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog I/O ports are left open.

HP8753ES setup

Average = 4
RBW = 3 kHz
 $V_{BIAS} = 0.35$ V
ST = 2 s
P1 = 0 dBm

PARAMETER MEASUREMENT INFORMATION



† A 50-Ω termination resistor is needed for the network analyzer.

Figure 6. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IB_0 . All unused analog input (Y) ports are connected to GND and output (I) ports are connected to GND through 50-Ω pulldown resistors.

HP8753ES setup

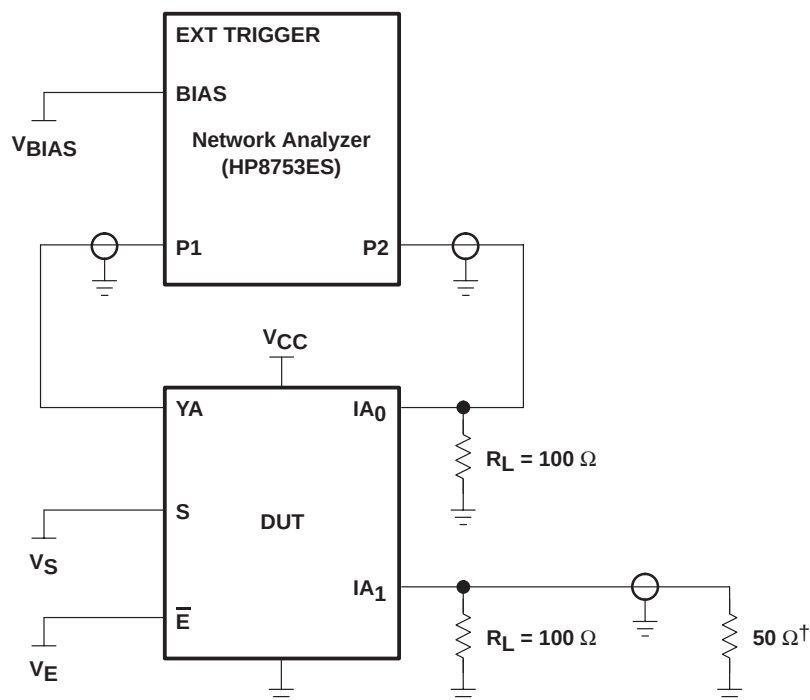
Average = 4
 RBW = 3 kHz
 $V_{BIAS} = 0.35\text{ V}$
 ST = 2 s
 P1 = 0 dBm

TS3L100

QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A – MAY 2004 – REVISED OCTOBER 2004

PARAMETER MEASUREMENT INFORMATION



† A 50-Ω termination resistor is needed for the network analyzer.

Figure 7. Test Circuit for Off Isolation (O_{IRR})

OFF isolation is measured at the output of the OFF channel. For example, when $V_S = V_{CC}$, $V_E = 0$, and YA is the input, the output is measured at IA_0 . All unused analog input (Y) ports are left open and output (I) ports are connected to GND through 50-Ω pulldown resistors.

HP8753ES setup

Average = 4
RBW = 3 kHz
 $V_{BIAS} = 0.35$ V
ST = 2 s
P1 = 0 dBm

PARAMETER MEASUREMENT INFORMATION

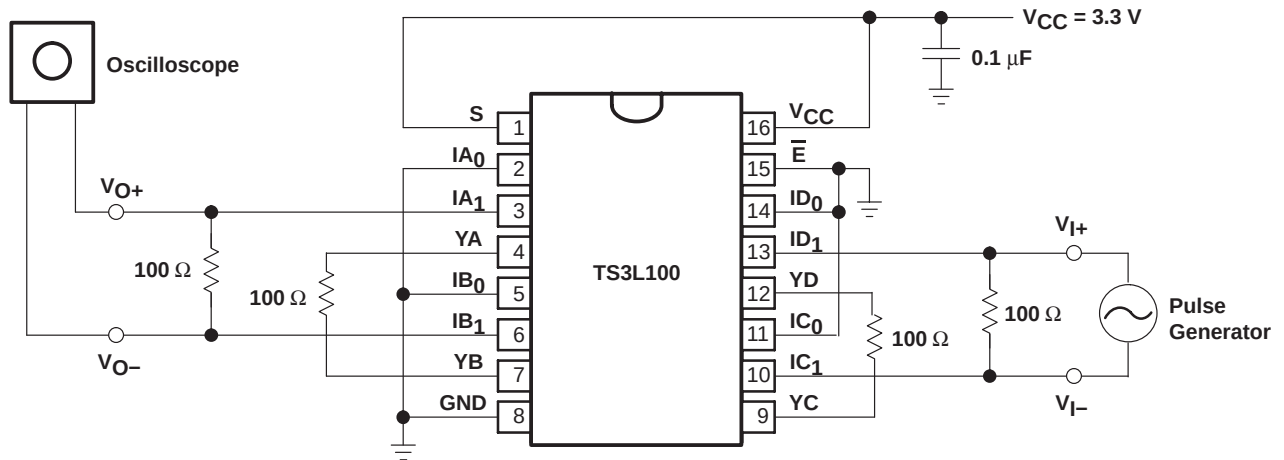


Figure 8. Differential Crosstalk Measurement

Differential crosstalk is a measure of coupling noise between a transmit and receive pair in the LAN application. Differential crosstalk depends on the edge rate, frequency, and load. This is calculated from the equation, $X_{TALK}(Diff) \text{ db} = 20 \log V_O(Diff)/V_I(Diff)$, where $V_O(Diff)$ is the differential output voltage and $V_I(Diff)$ is the differential input voltage.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS3L100DBQR	Active	Production	SSOP (DBQ) 16	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TK100
TS3L100DBQR.B	Active	Production	SSOP (DBQ) 16	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TK100
TS3L100DGVR	Active	Production	TVSOP (DGV) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100
TS3L100DGVR.B	Active	Production	TVSOP (DGV) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100
TS3L100DR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TS3L100
TS3L100DR.B	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TS3L100
TS3L100PW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100
TS3L100PW.B	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100
TS3L100PWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100
TS3L100PWR.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100
TS3L100RGYR	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TK100
TS3L100RGYR.B	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TK100

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

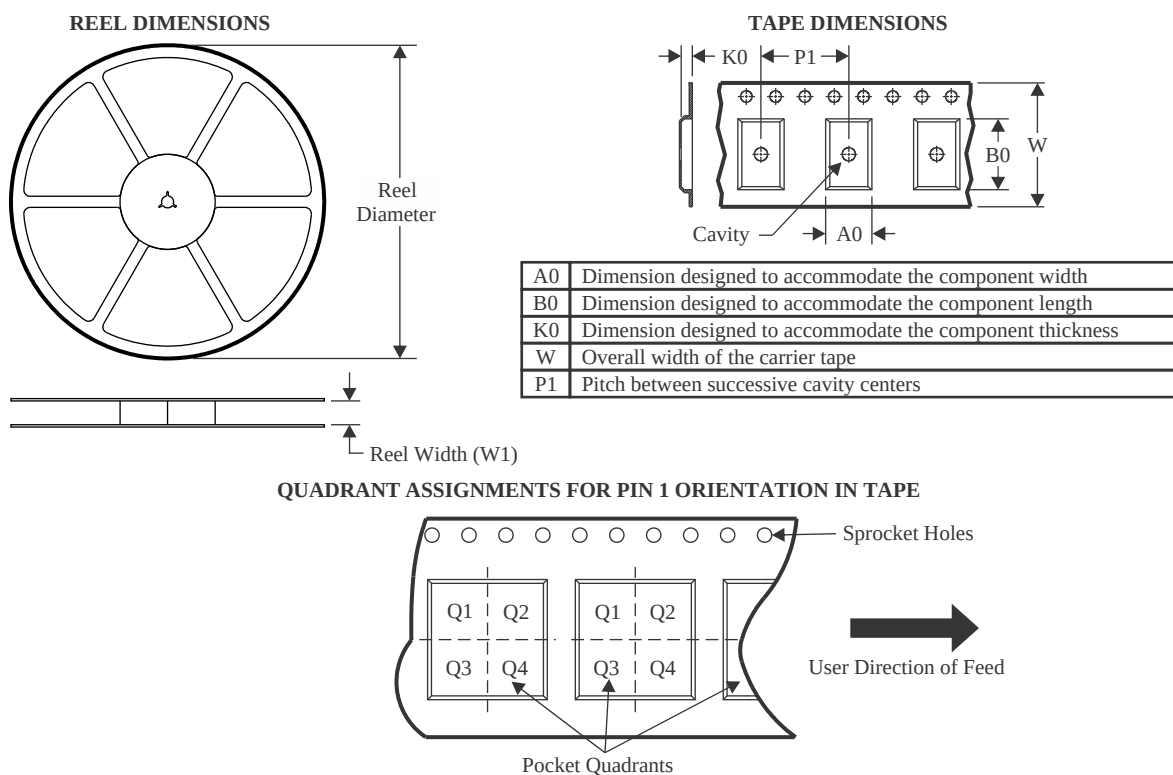
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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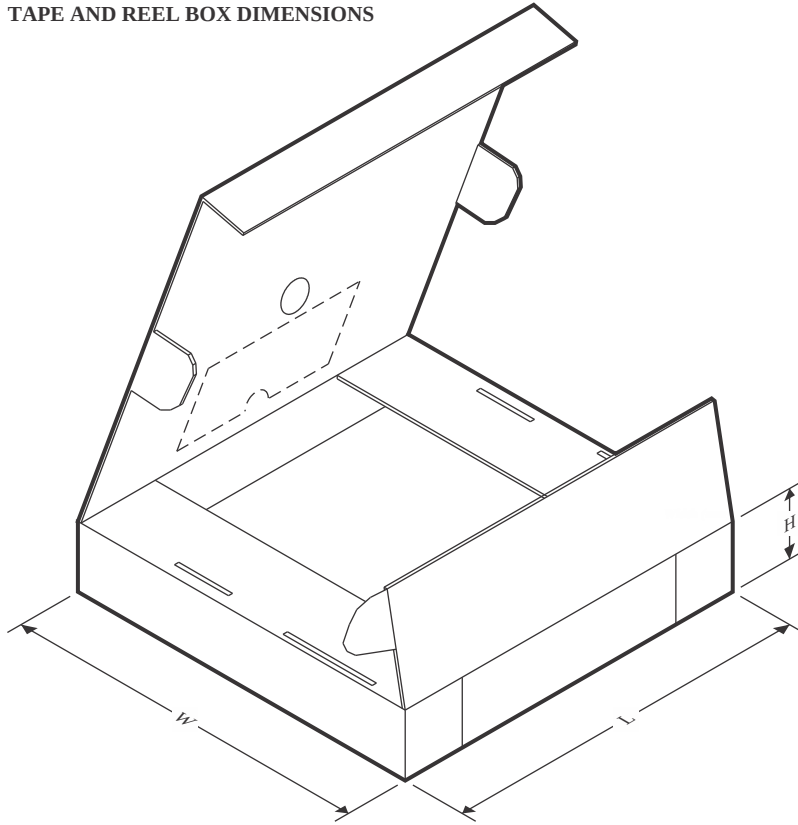
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3L100DBQR	SSOP	DBQ	16	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
TS3L100DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
TS3L100DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TS3L100PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TS3L100RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1

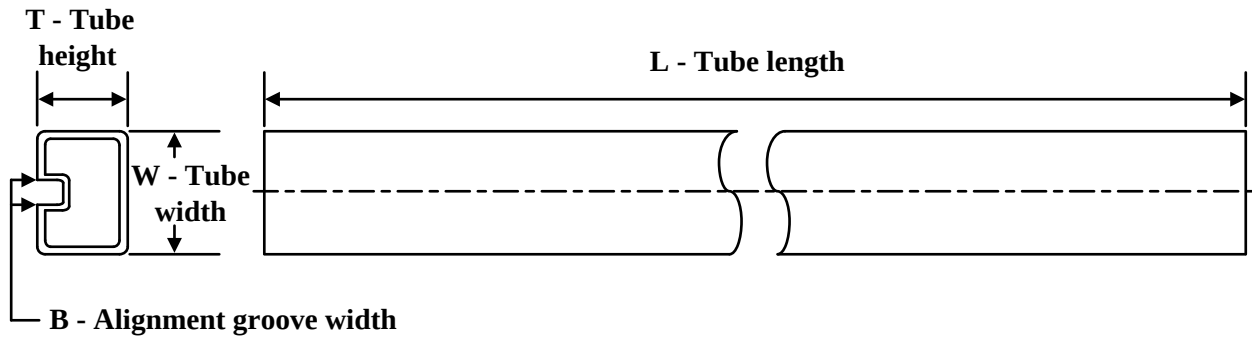
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3L100DBQR	SSOP	DBQ	16	2500	353.0	353.0	32.0
TS3L100DGVR	TVSOP	DGV	16	2000	353.0	353.0	32.0
TS3L100DR	SOIC	D	16	2500	340.5	336.1	32.0
TS3L100PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
TS3L100RGYR	VQFN	RGY	16	3000	353.0	353.0	32.0

TUBE

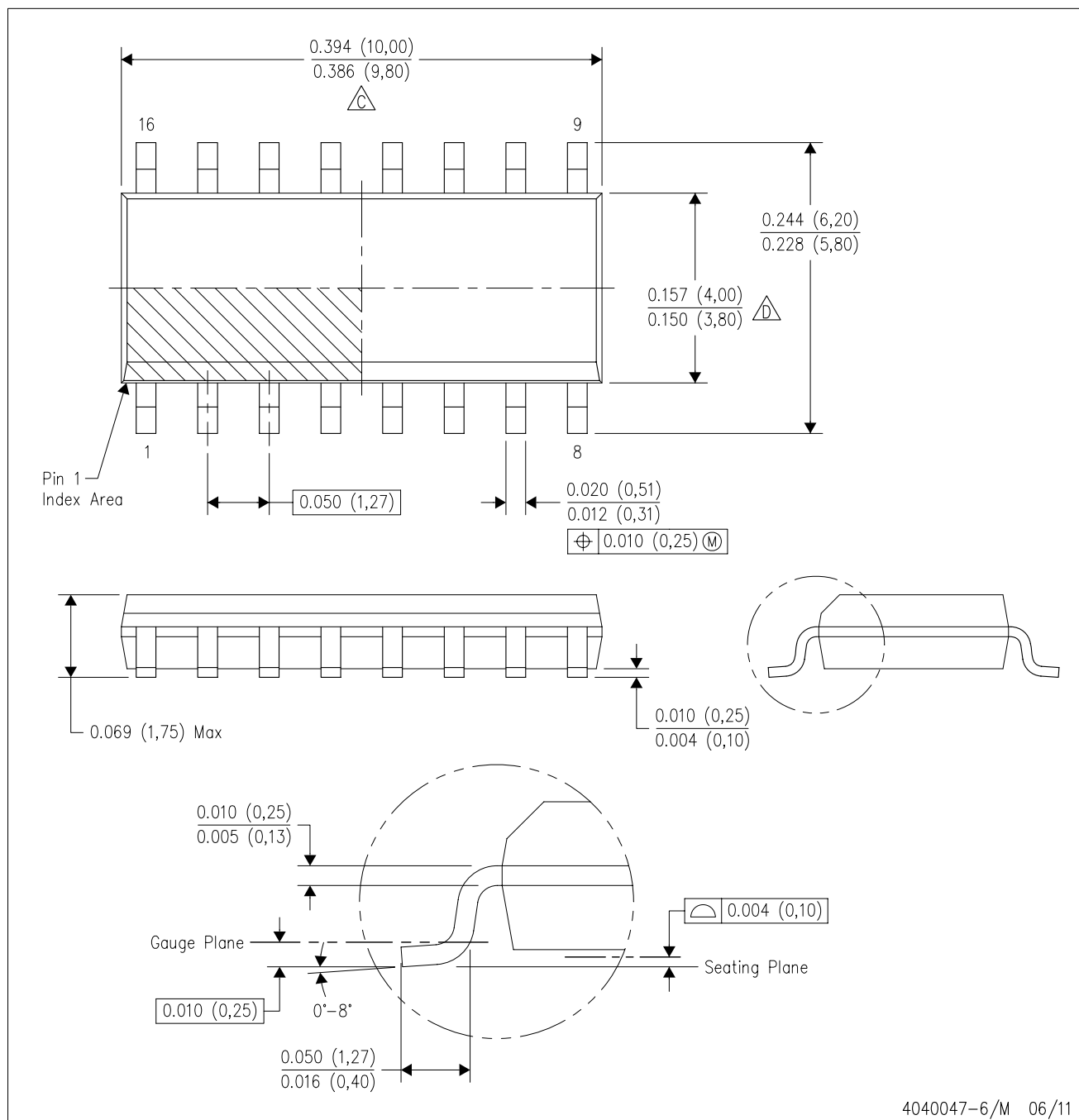


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TS3L100PW	PW	TSSOP	16	90	530	10.2	3600	3.5
TS3L100PW.B	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE

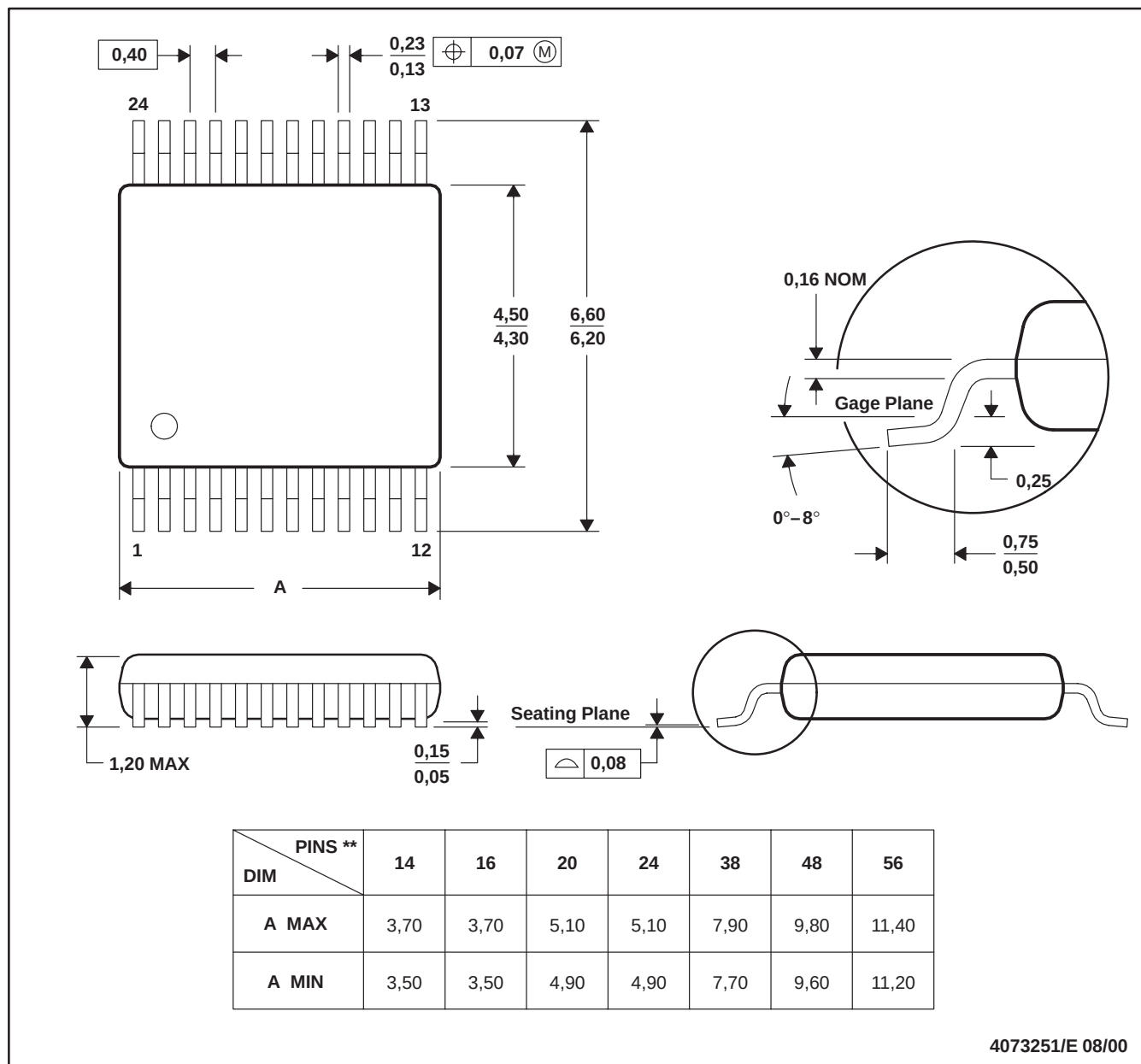


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

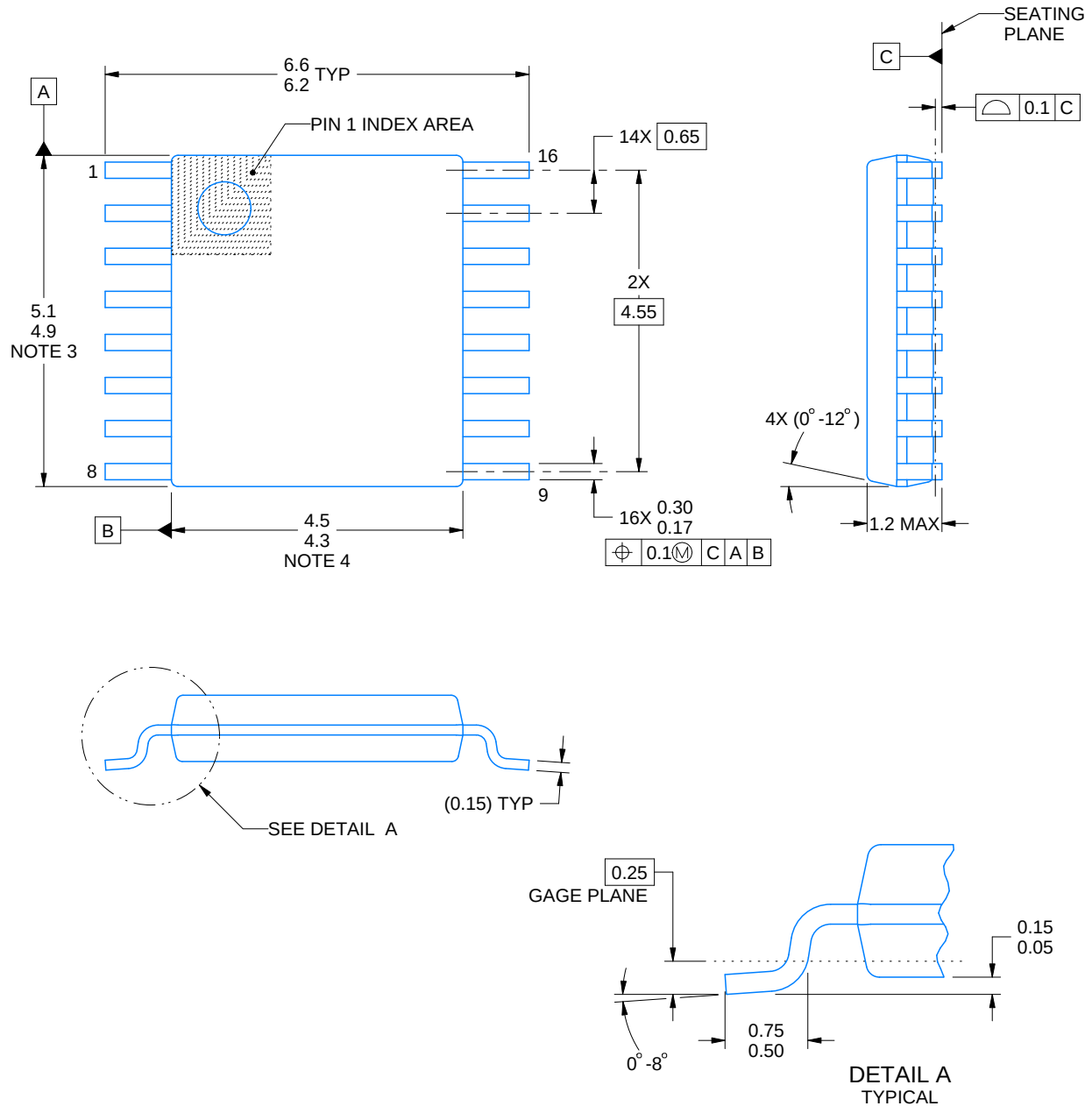
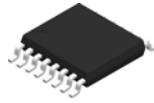
DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194



4220204/B 12/2023

NOTES:

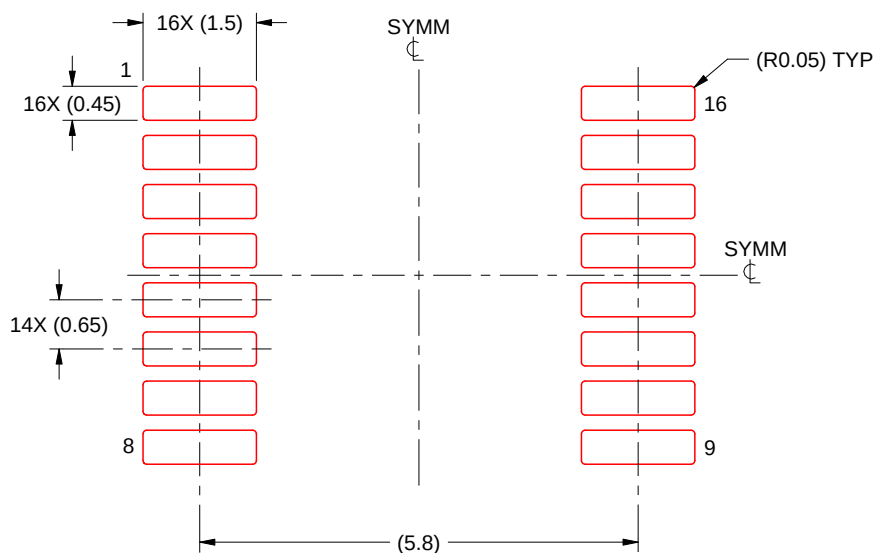
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

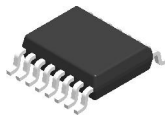


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

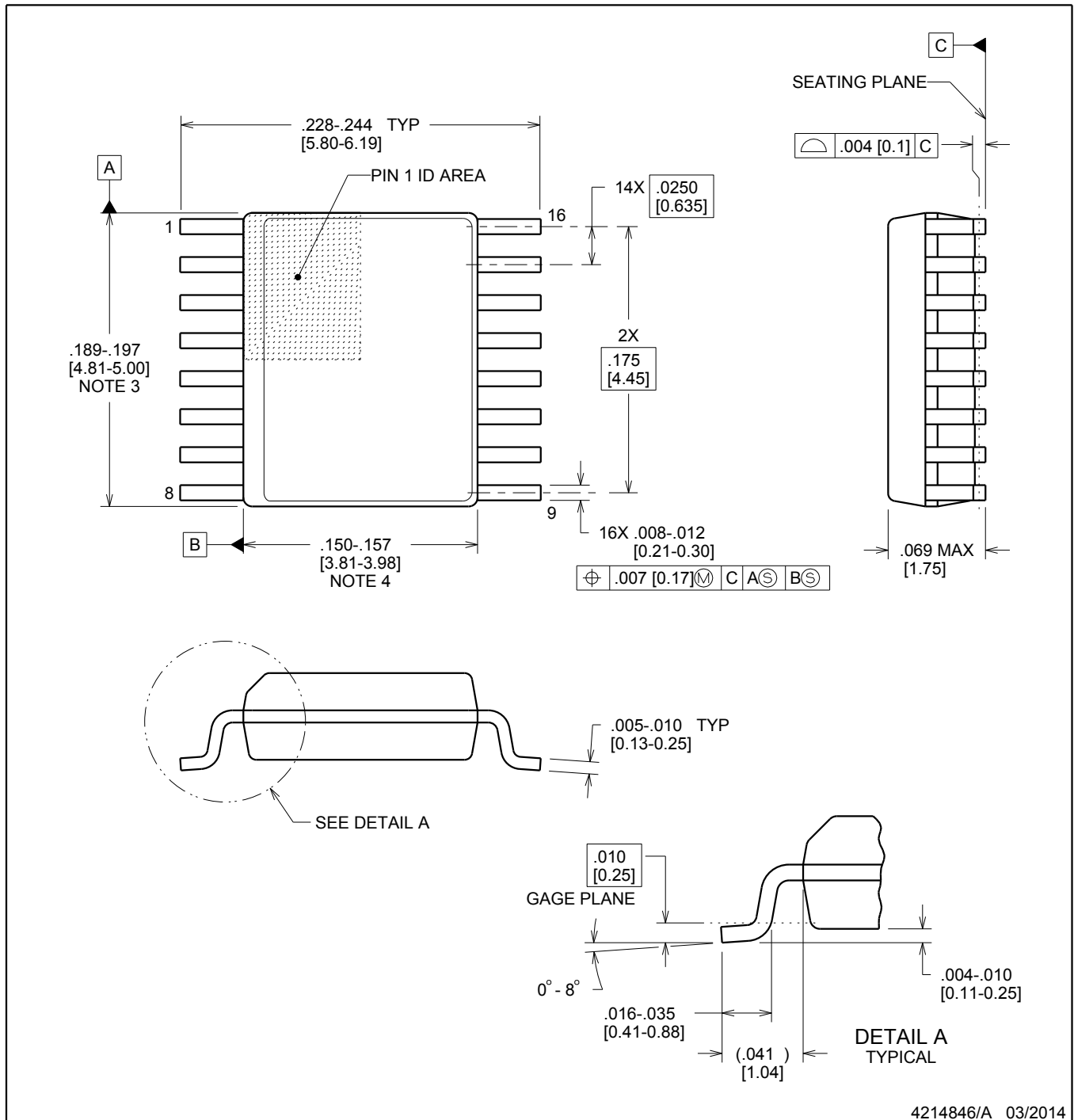


DBQ0016A

PACKAGE OUTLINE

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



4214846/A 03/2014

NOTES:

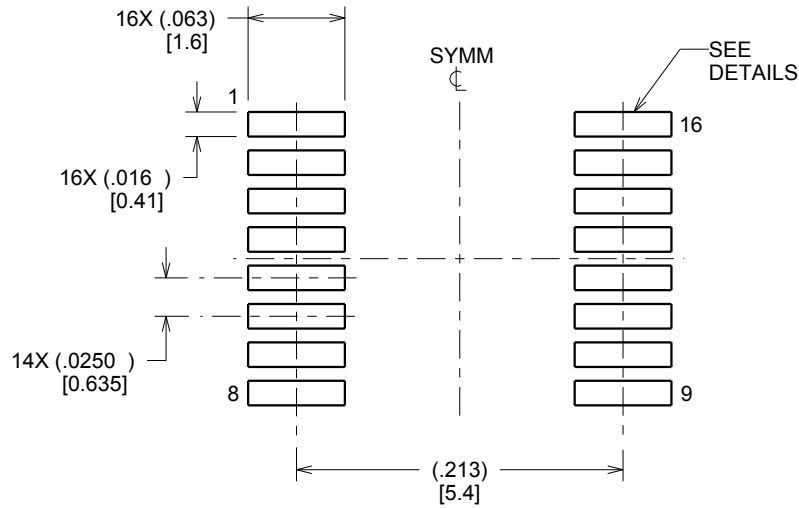
- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MO-137, variation AB.

EXAMPLE BOARD LAYOUT

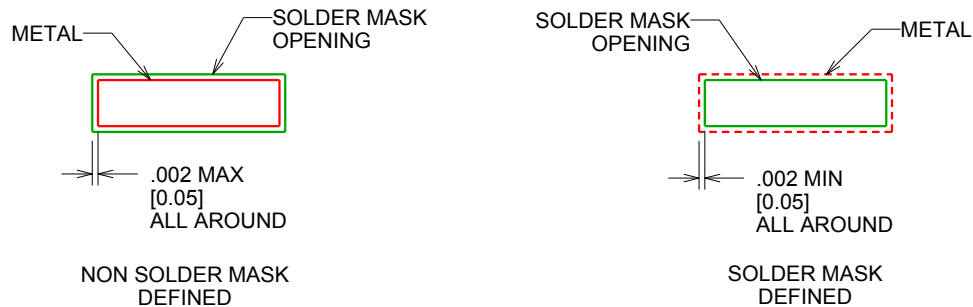
DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4214846/A 03/2014

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

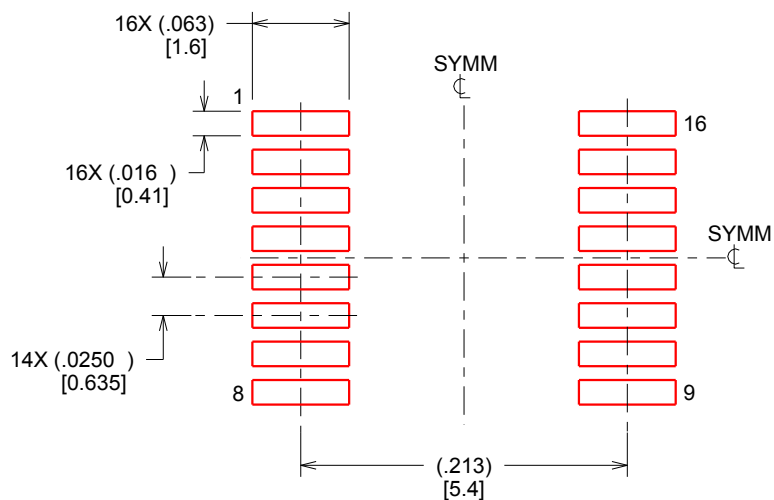
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.127 MM] THICK STENCIL
SCALE:8X

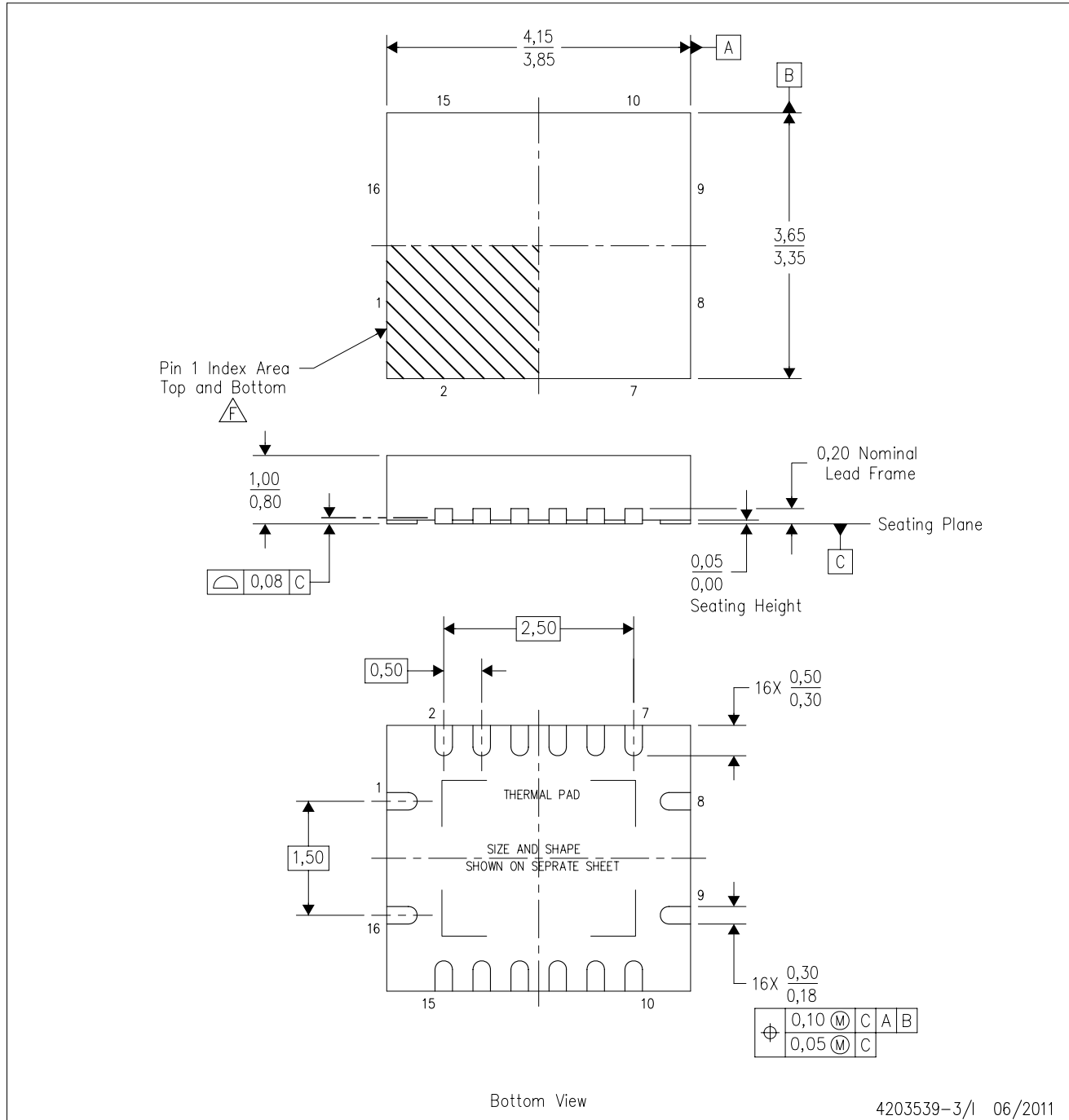
4214846/A 03/2014

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-3/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F** Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N16)

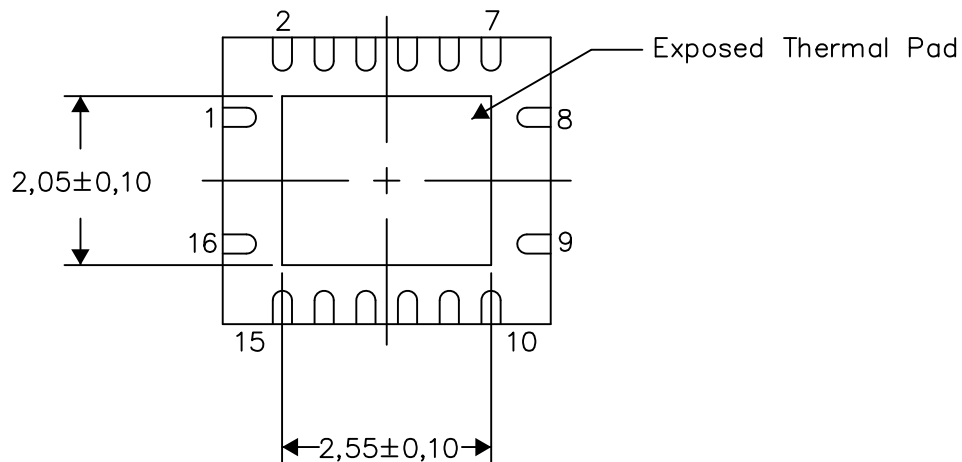
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

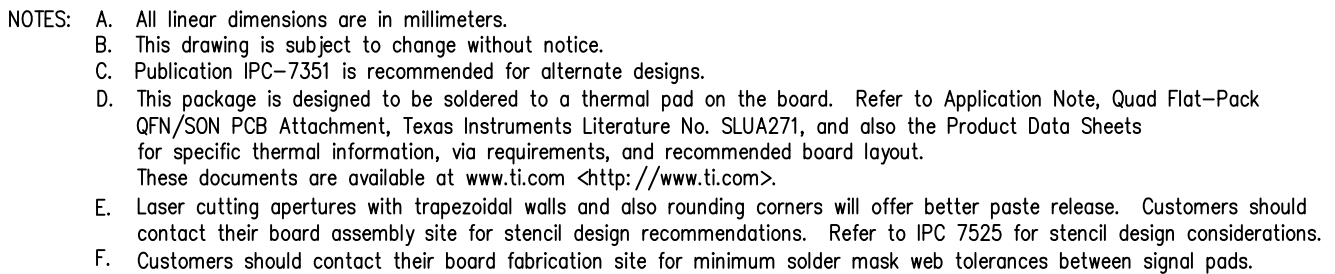


Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



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